

# **Spectrum Devices Corporation**

**Semiconductor Engineering and Manufacturing** 

## RF & MICROWAVE TRANSISTORS HF SSB APPLICATIONS

HF12-125

### **FEATURES:**

- 30 MHz
- 12.5 Volts
- IMD -30 dB
- Common Emitter
- Gold Metallization
- P<sub>out</sub>= 125W PEP Min. with 12 dB Gain



• Equivalent to the ST SD1487, with Enhanced Output Power



0.500" DIAMETER SOE PACKAGE

#### **DESCRIPTION:**

The HF12-125 is a 12.5V epitaxial silicon NPN planar transistor designed primarily for HF communications. This device utilizes emitter ballasting to achieve extreme ruggedness under severe operating conditions. The HF12-series products utilize the unique Spectrum Devices' Bipolar process which offers a 67% improvement in collector-base breakdown voltage, enhancing reliability while maintaining RF performance.

## ABSOLUTE MAXIMUM RATINGS: $(T_{CASE} = 25^{\circ}C)$

| Symbol            | Parameter                 | Value       | Unit |
|-------------------|---------------------------|-------------|------|
| V <sub>CBO</sub>  | Collector-Base Voltage    | 60          | V    |
| V <sub>CEO</sub>  | Collector-Emitter Voltage | 18          | V    |
| V <sub>EBO</sub>  | Emitter-Base Voltage      | 4.0         | V    |
| $I_{\rm C}$       | Device Current            | 20          | A    |
| P <sub>DISS</sub> | Total Dissipation         | 290         | W    |
| $T_{J}$           | Junction Temperature      | +200        | °C   |
| T <sub>STG</sub>  | Storage Temperature       | -65 to +150 | °C   |

## THERMAL DATA:

| R <sub>TH(J-C)</sub> | Thermal Resistance Junction-case | 0.6 | °C/W |
|----------------------|----------------------------------|-----|------|

# $\underline{ELECTRICAL\ SPECIFICATIONS}\ (T_{CASE}=25^{\circ}C)$

## **DC CHARACTERISTICS**

| Symbol            | Test Conditions              |                      |      | T1 .*4 |      |      |
|-------------------|------------------------------|----------------------|------|--------|------|------|
|                   |                              |                      | Min. | Тур.   | Max. | Unit |
| BV <sub>CBO</sub> | $I_C = 100 \text{ mA}$       | $I_E = 0 mA$         | 60   |        |      | V    |
| BV <sub>CES</sub> | $I_C = 100 \text{ mA}$       | $V_{BE} = 0 V$       | 60   |        |      | V    |
| BV <sub>CEO</sub> | $I_{\rm C} = 100 \text{ mA}$ | $I_B = 0 \text{ mA}$ | 18   |        |      | V    |
| BV <sub>EBO</sub> | $I_E = 20 \text{ mA}$        | $I_C = 0 \text{ mA}$ | 4.0  |        |      | V    |
| I <sub>CES</sub>  | $V_{CE} = 15 \text{ V}$      | $I_E = 0 \text{ mA}$ |      |        | 20   | mA   |
| h <sub>FE</sub>   | $V_{CE} = 5 V$               | $I_C = 5 A$          | 10   |        | 200  |      |

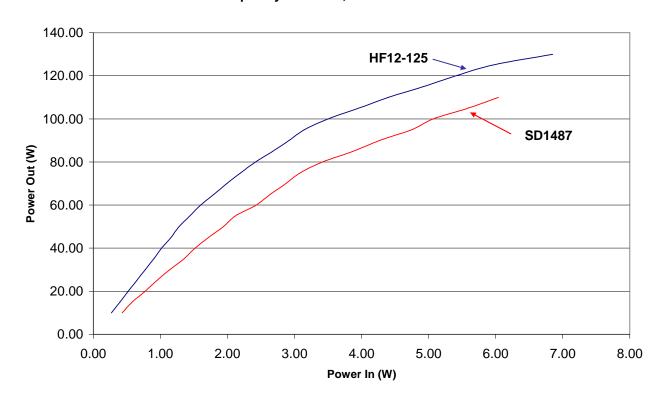
## **RF CHARACTERISTICS**

|                     | l Test Conditions                         |                         | Value                     |      |      |      |     |
|---------------------|---|-------------------------|---------------------------|------|------|------|-----|
| Symbol              |   |                         | Min.                      | Тур. | Max. | Unit |     |
| Pout                | <b>f</b> = 30 MHz                         | $V_{\rm CC}$ = 12.5 V   | $I_{CQ} = 150 \text{ mA}$ | 125  |      |      | W   |
| G <sub>P</sub>      | <b>P</b> <sub>out</sub> =125 <b>W PEP</b> | $V_{\rm CC}$ = 12.5 V   | $I_{CQ} = 150 \text{ mA}$ | 12   |      |      | dB  |
| IMD*                | <b>P</b> <sub>out</sub> =125 <b>W PEP</b> | $V_{\rm CC}$ = 12.5 $V$ | $I_{CQ} = 150 \text{ mA}$ |      |      | -30  | dBc |
| $\eta_{\mathrm{C}}$ | <b>P</b> <sub>out</sub> =125 W <b>PEP</b> | $V_{\rm CC}$ = 12.5 $V$ | $I_{CQ} = 150 \text{ mA}$ | 40   |      |      | %   |
| C <sub>OB</sub>     | f = 1 MHz                                 | $V_{CB} = 12.5 V$       |                           |      | 400  |      | pF  |

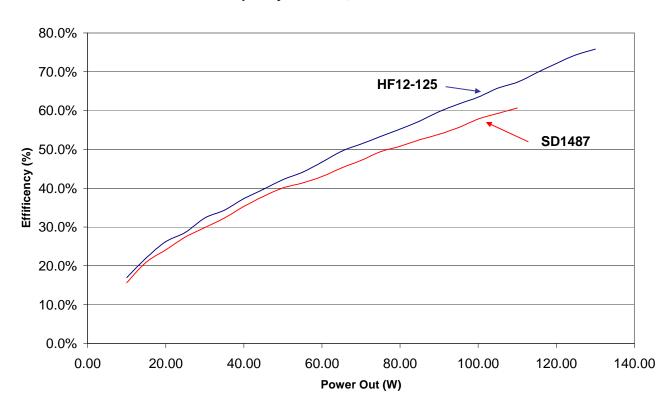
\*Conditions f1 = 30.00MHz f2 = 30.001MHz

### TYPICAL PERFORMANCE

#### Power In vs. Power Out Frequency = 30 MHz, Vcc = 12.5 Volts

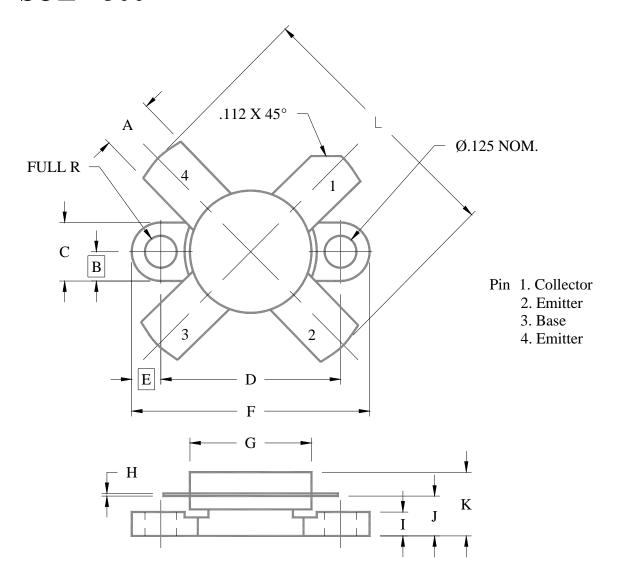


Efficiency vs Power Out Frequency = 30 MHz, Vcc = 12.5 Volts



# PACKAGE MECHANICAL DATA

# **SOE - 500**



|   | Minimum    | Maximum    |   | Minimum    | Maximum     |
|---|------------|------------|---|------------|-------------|
|   | Inches/MM  | Inches/MM  |   | Inches/MM  | Inches/MM   |
| A | .220/5.59  | .230/5.84  | G | .495/12.57 | .505/12.83  |
| В | .125/3.18  |            | Н | .003/0.08  | .007/0.18   |
| C | .245/6.22  | .255/6.48  | Ι | .090/2.29  | .110/2.79   |
| D | .720/18.28 | .730/18.54 | J | .160/4.06  | .175/4.45   |
| E | .125/3.18  |            | K |            | .280/7.11   |
| F | .970/24.64 | .980/24.89 | L |            | 1.050/26.67 |

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